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LV52205MU

Bi-CMOS IC

LED Boost Driver with PWM Dimming

Overview

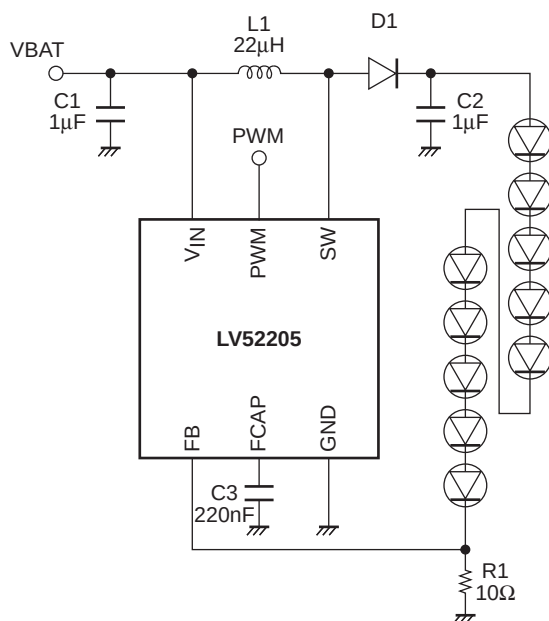
The LV52205MU is a high voltage boost driver for LED drive. LED current is set by the external resistor R1 and LED dimming can be done by changing FB voltage with PWM control.

Features

- Operating Voltage from 2.7V to 5.5V
- PWM dimming for Brightness Control
- Integrated 42V MOSFET
- 600kHz Switching Frequency

Typical Applications

- LED Display Backlight Control



ORDERING INFORMATION

See detailed ordering and shipping information on page 8 of this data sheet.

Specifications

Absolute Maximum Ratings at $T_a = 25^{\circ}\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	$V_{CC\text{ max}}$	V_{CC}	5.5	V
Maximum pin voltage1	$V1\text{ max}$	SW	42	V
Maximum pin voltage2	$V2\text{ max}$	Other pin	5.5	V
Allowable power dissipation	$Pd\text{ max}$	$T_a = 25^{\circ}\text{C} *1$	2.05	W
Operating temperature	T_{opr}		-30 to +85	$^{\circ}\text{C}$
Storage temperature	T_{stg}		-55 to +125	$^{\circ}\text{C}$

*1 Mounted on a specified board: 70mm×50mm×1.2mm (4 layer glass epoxy)

Caution 1) Absolute maximum ratings represent the values which cannot be exceeded for any length of time.

Caution 2) Even when the device is used within the range of absolute maximum ratings, as a result of continuous usage under high temperature, high current, high voltage, or drastic temperature change, the reliability of the IC may be degraded. Please contact us for the further details.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

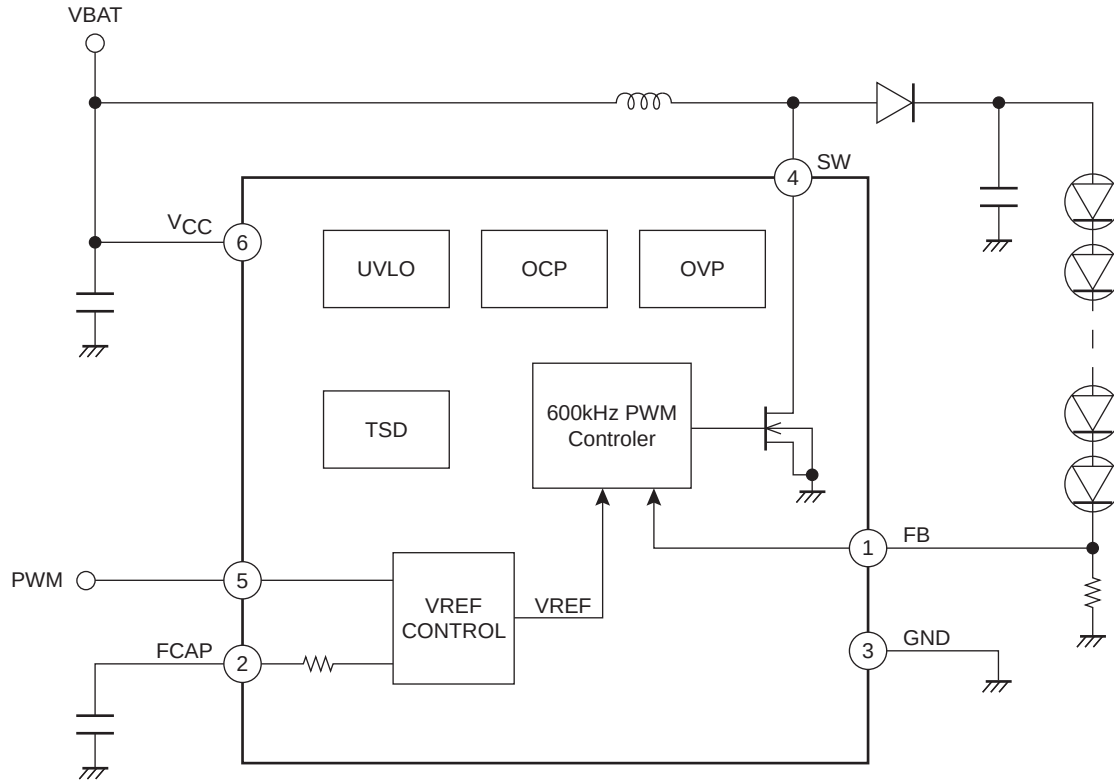
Recommendation Operating Condition at $T_a = 25^{\circ}\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage range1	$V_{CC\text{ op}}$	V_{CC}	2.7 to 5.5	V
PWM frequency	F_{pwm}		300 to 100k	Hz

Electrical Characteristics Analog block at $T_a = 25^{\circ}\text{C}$, $V_{CC} = 3.6\text{V}$, unless otherwise specified

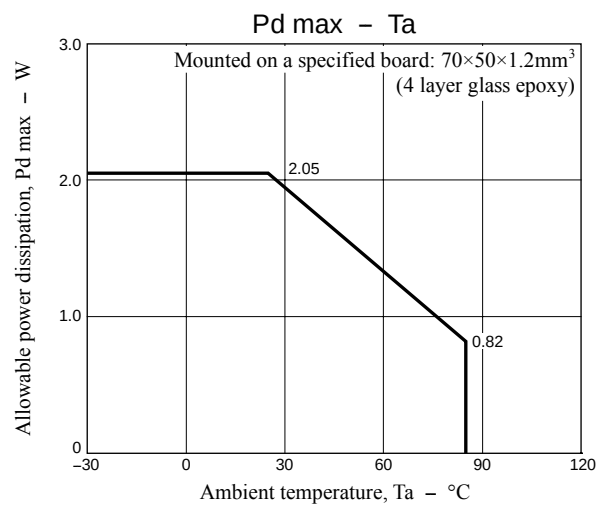
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Standby current dissipation	I_{CC1}	SHUTDOWN		0	5	μA
DC/DC current dissipation	I_{CC2}	$V_{OUT} = 30\text{V}$, $I_{LED} = 20\text{mA}$			1	mA
FB voltage	V_{fb}	PWM duty 100%	0.19	0.2	0.21	V
FB pin leak current	I_{fb}				1	μA
OVP voltage	V_{ovp}	SW	40	41	42	V
SWOUT ON resistance	R_{on}	$I_L = 100\text{mA}$		700		$\text{m}\Omega$
NMOS switch current limit	I_{LIM}	$V_{fb} = 200\text{mV}$		0.7		A
OSC frequency	F_{osc}			600		kHz
High level input voltage	V_{INH}	PWM	1.5		V_{CC}	V
Low level input voltage	V_{INL}	PWM	0		0.4	V
Under voltage lockout	V_{uvlo}	V_{IN} falling		2.2		V
PWM setup time from shutdown	T_{on}		20			μs
PWM low time to shutdown	T_{off}		8.9			ms

Block Diagram



Pin Function

PIN #	Pin Name	Description
1	FB	Feedback pin.
2	FCAP	Filtering capacitor terminal for PWM signal.
3	GND	Ground
4	SW	Switch pin. Drain of the internal power FET.
5	PWM	PWM dimming input (active High).
6	V _{CC}	Supply voltage.
	Expose-pad	Connect to GND on PCB.



LED Current Setting

LED current is set by an external resistor connected between the FB pin and ground.

$$I_{LED} = V_{FB}/R_{FB}.$$

The V_{FB} can be controlled by PWM signal. PWM input is converted into a near DC current by the internal resistor R that was equivalent to $60k\Omega (\pm 10\%)$ and the external capacitor C_{FCAP} as a low pass filter with a cut-off frequency $f_c = 1/2\pi RC_{FCAP}$. The V_{FB} can be adjusted by altering the duty cycle of the PWM signal (See Fig.1).

$$V_{FB} = 200 \text{ (mV)} \times \text{PWM Duty (\%)}$$

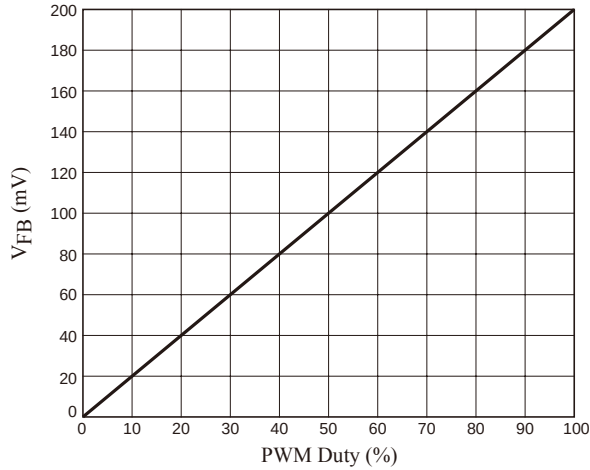


Fig1. V_{FB} vs. PWM Duty

PWM Control

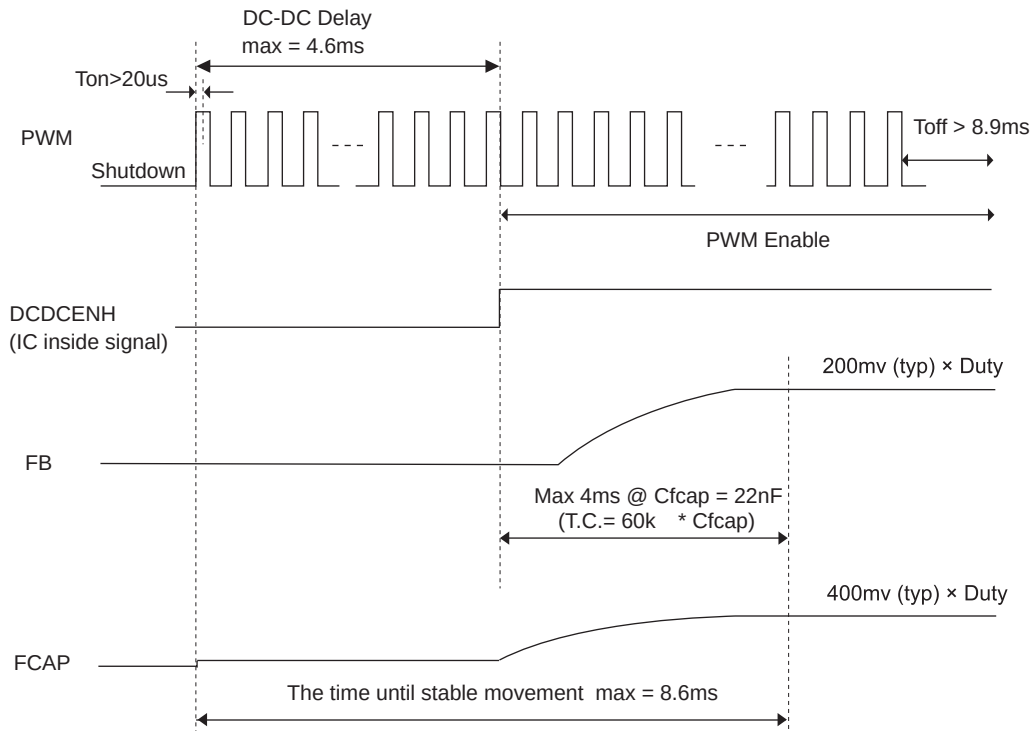


Fig2. Timing Diagram in PWM signal

Open LED Protection

If SW terminal voltage exceeds a threshold V_{ovp} (41V typ) for 8 cycles, boost converter enters shutdown mode. In order to restart the IC, PWM setup signal is required again.

Over Current Protection

Current limit value for built-in power MOS is around 0.7A. The power MOS is turned off for each switching cycle when peak current through it exceeds the limit value.

Under Voltage Lock Out (UVLO)

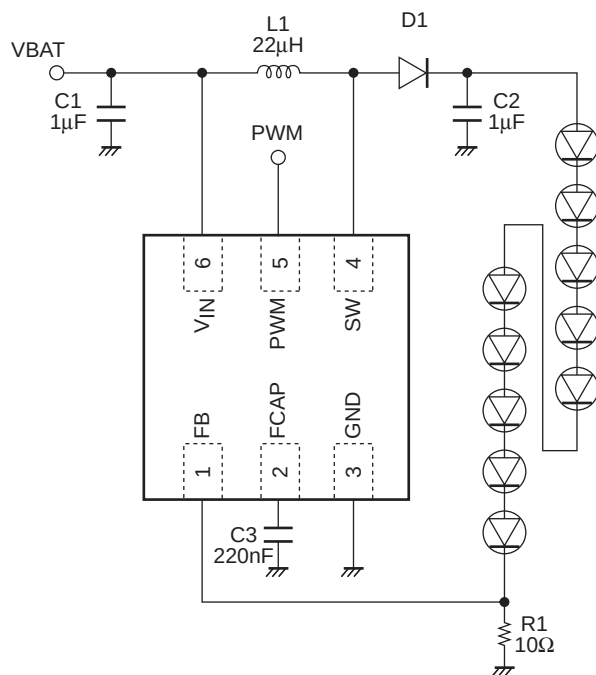
UVLO operation works when V_{IN} terminal voltage is below 2.2V.

Thermal Shutdown

When chip temperature is too high, boost converter is stopped.

Application Circuit Diagram

10LEDs

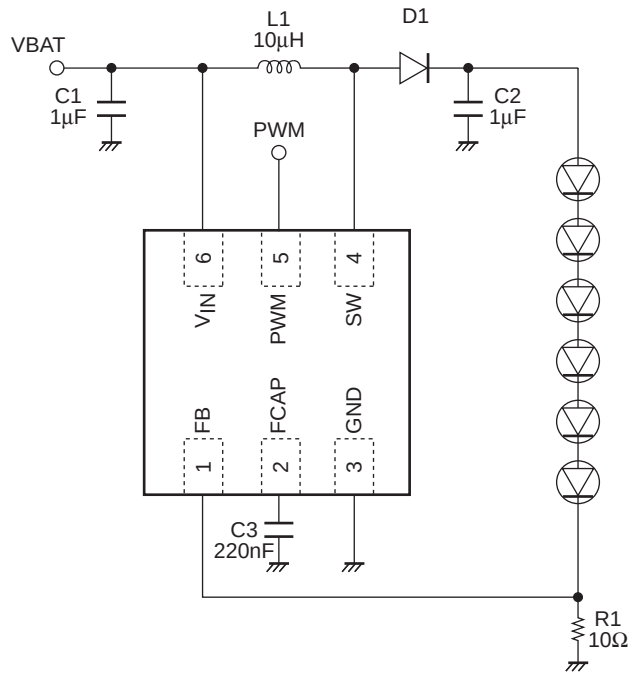


L1: VLS3012T-220M49 (TDK), VLF504015MT-220M (TDK)

D1: MBR0540T1 (ON semi), NSR05F40 (ONsemi)

C2: GRM21BR71H105K (Murata), C1608X5R1H105K (TDK)

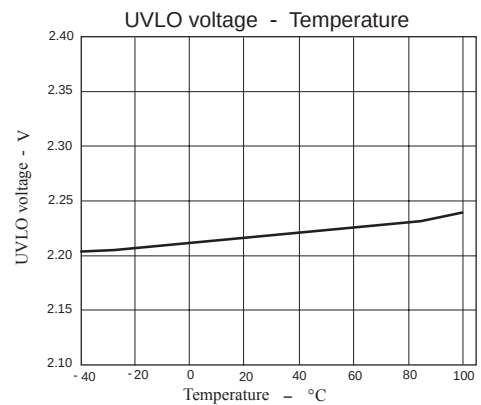
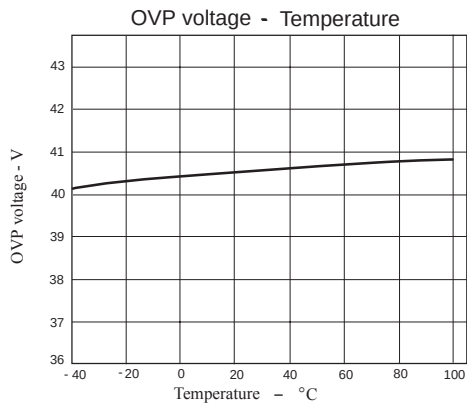
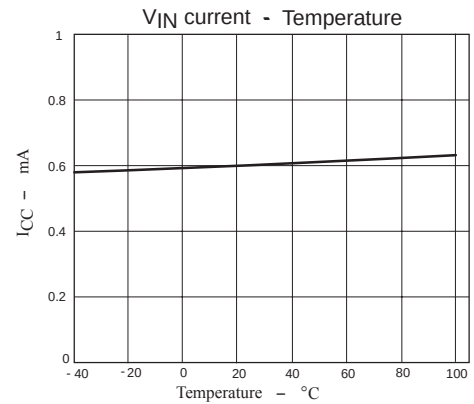
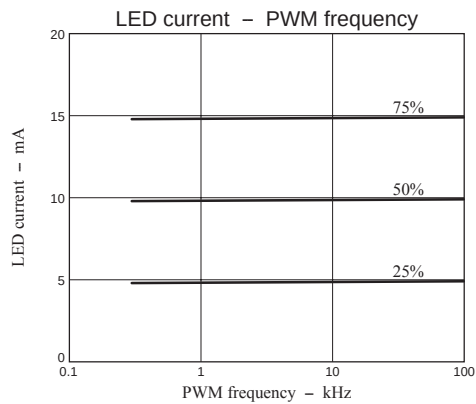
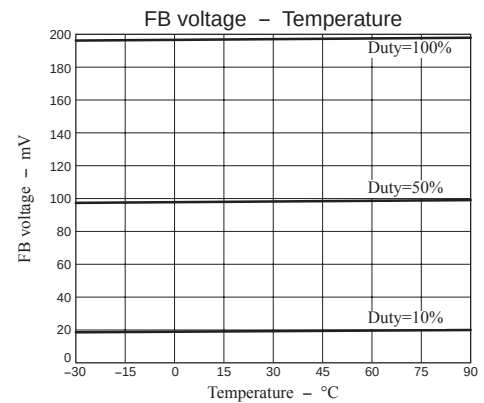
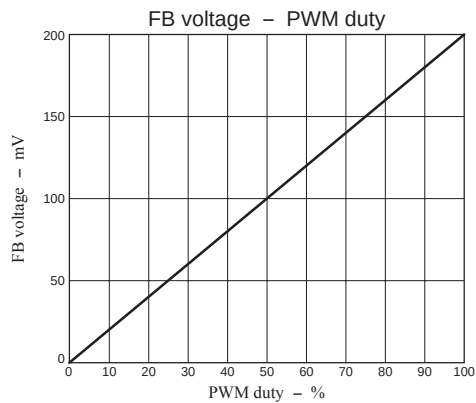
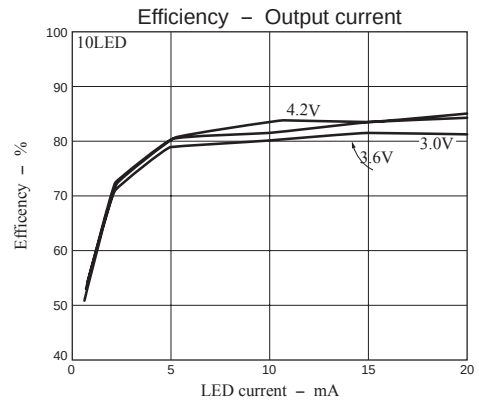
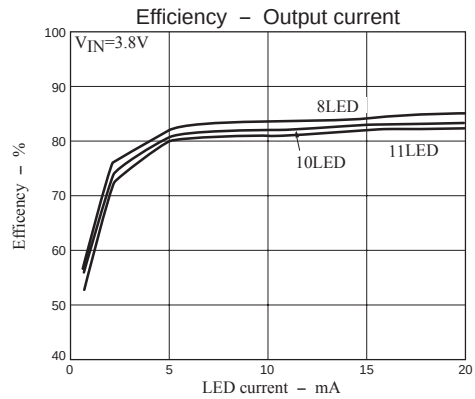
6LEDs



L1: VLS3012T-100M72 (TDK), VLF302512M-100M (TDK)
D1: MBR0540T1 (ON semi), NSR05F40 (ONsemi)
C2: GRM21BR71H105K (Murata), C1608X5R1H105K (TDK)

LV52205MU

Typical Characteristics ($V_{IN} = 3.6V$, $L = 22\mu H$, $T = 25^{\circ}C$, unless otherwise specified)



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